

# SANYO Semiconductors DATA SHEET

# MCH6423 — General-Purpose Switching Device Applications

#### **Features**

· 4V drive.

## **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	٧
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		2	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	8	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (1200mm <sup>2</sup> X0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Drain-to-Source Breakdown Voltage	V(BR)DSS	I <sub>D</sub> =1mA, V <sub>G</sub> S=0V	60			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =1A	1.3	2.2		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=1A, VGS=10V		170	220	mΩ
	R <sub>DS</sub> (on)2	I <sub>D</sub> =0.5A, V <sub>G</sub> S=4V		210	300	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =20V, f=1MHz		220		pF
Output Capacitance	Coss	V <sub>DS</sub> =20V, f=1MHz		28		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =20V, f=1MHz		20		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		8		ns
Rise Time	tr	See specified Test Circuit.		5.3		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		26		ns
Fall Time	tf	See specified Test Circuit.		21		ns

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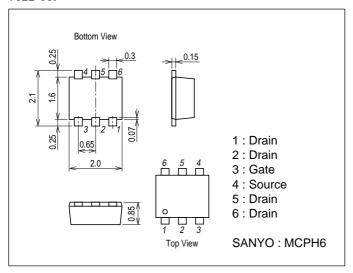
## MCH6423

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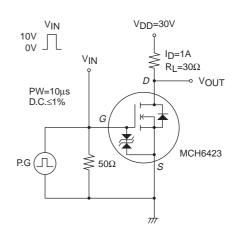
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Total Gate Charge	Qg	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		6.4		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		1.1		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =30V, V <sub>GS</sub> =10V, I <sub>D</sub> =2A		1.1		nC
Diode Forward Voltage	VSD	IS=2A, VGS=0V		0.85	1.2	V

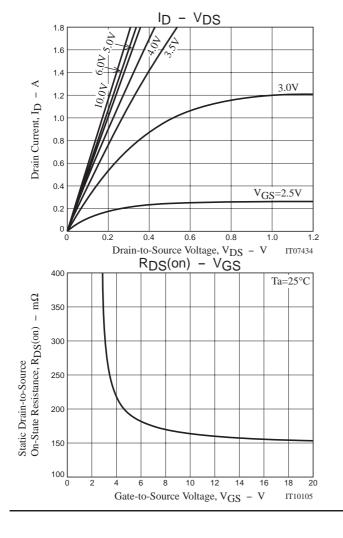
#### **Package Dimensions**

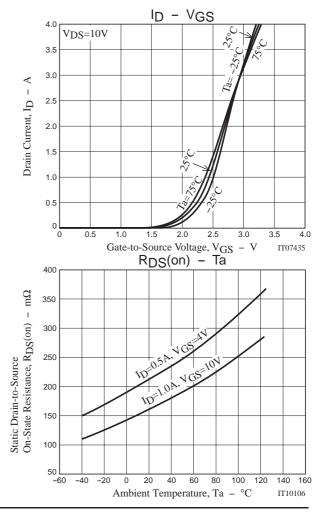
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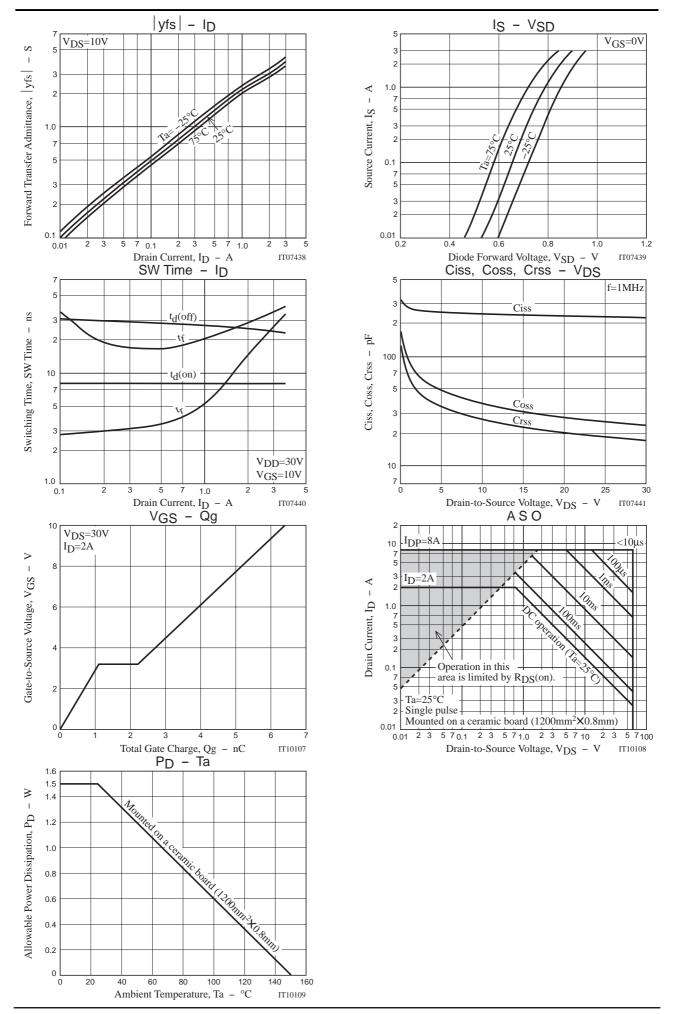


#### **Switching Time Test Circuit**









Note on usage: Since the MCH6423 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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